# SENSITRON SEMICONDUCTO

# RKBPC10, 15, 25, 35/W

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Hole for #8 screw, 4.90Ø Nominal

All Dimension in mm

0.97Ø

1.07Ø

6.35 Typical

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## 10, 15, 25, 35A FAST RECOVERY BRIDGE RECTIFIER

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## Data sheet 1323 Rev.—

### Features

- Diffused Junction
- Low Reverse Leakage Current
- Fast Switching, High Efficiency
- Electrically Isolated Epoxy Case for Maximum Heat Dissipation
- Case to Terminal Isolation Voltage 2500V

#### D C D ¥ Н F Metal Heat Sink RKBPC **RKBPC-W RKBPC-W** RKBPC Dim Min Max Min Max 28.40 28.70 28.40 28.70 Α в 10.97 10.97 11.23 11.23 С 15.70 16.70 17.10 19.10 D 17.50 18.50 10.90 11.90 Ε 22.86 25.40 30.50

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### **Mechanical Data**

- Case: Epoxy Case with Heat Sink Internally Mounted in the Bridge Encapsulation
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Symbols Marked on Case
- Mounting: Through Hole for #8 Screw
- Weight: RKBPC 24 grams (approx.) RBPC-W 21 grams (approx.)
- Marking: Type Number

"W" Suffix Designates Wire Leads No Suffix Designates Faston Terminals

\*All Models are Available on B(Height)=7.62mm Max. Epoxy Case

## Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristics	Symbol	-00/W	-01/W	-02/W	-04/W	-06/W	-08/W	-10/W	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	Vrrm Vrwm Vr	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	VR(RMS)	35	70	140	280	420	560	700	V
Average Rectifier Output Current @T <sub>c</sub> = 55°C RKBPC15/W RKBPC25/W RKBPC35/W	lo	10 15 25 35					A		
Non-Repetitive Peak Forward Surge Current 8.3ms single half sine-wave Superimposed on rated load (JEDEC Method)RKPBC10/W RKBPC25/W RKBPC35/W	IFSM	200 300 300 400					A		
Forward Voltage Drop (per element) RKBPC15/W $@I_F = 5.0A$ RKBPC15/W $@I_F = 7.5A$ RKBPC25/W $@I_F = 12.5A$ RKBPC35/W $@I_F = 17.5A$	Vfm	1.3				v			
Peark Reverse Current $@T_C = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_C = 125^{\circ}C$	Iгм	10 500						μA	
Reverse Recovery Time (Note 1)	trr		1:	50		250	50	00	nS



# Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

Typical Junction Capacitance (per element) (Note 2)	RKBPC10/W RKBPC15/W RKBPC25/W RKBPC35/W	Cj	200 200 300 400	pF
Typical Thermal Resistance Junction to Case (per element) (Note 3)	RKBPC10/W RKBPC15/W RKBPC25/W RKBPC35/W	R∂JC	6.3 6.3 3.8 3.8	K/W
RMS Isolation Voltage from Case to Lead		Viso	2500	V
Operating and Storage Temperature Range		Тј, Тѕтс	-65 to +125	°C

### \*Glass Passivated forms are available upon request.

Note: 1. Measured at  $I_F = 0.5A$ ,  $I_R = 1.0A$ ,  $I_{RR} = 0.25A$ .

2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

3. Thermal resistance junction to case mounted on heatsink.



0.01

20

40

60

80

PERCENT OF RATED PEAK REVERSE VOLTAGE (%) Fig. 5 Typical Reverse Characteristics (per element)

100

120

140